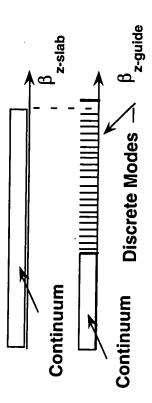
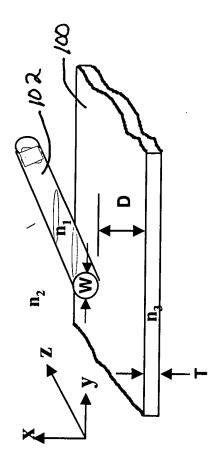
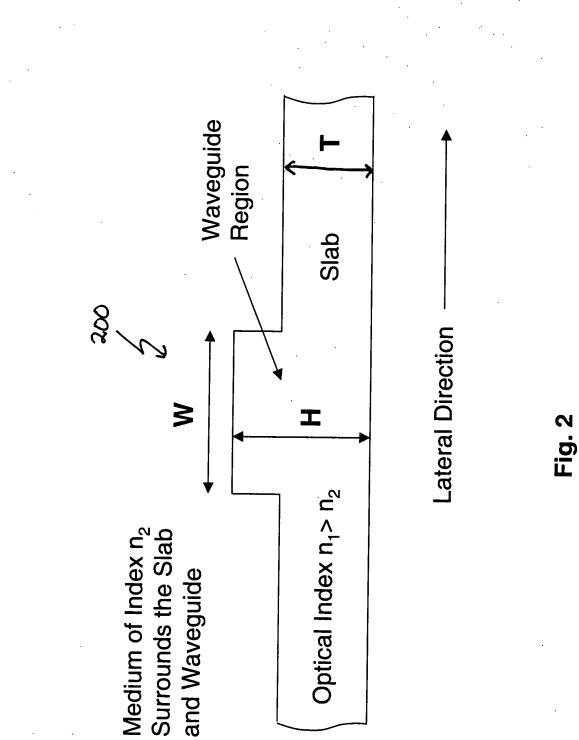
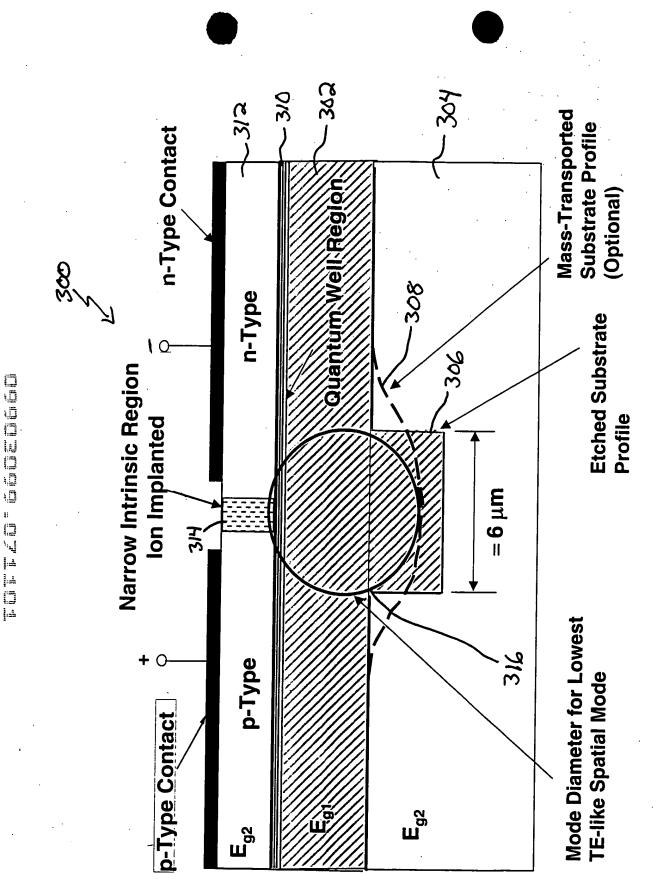
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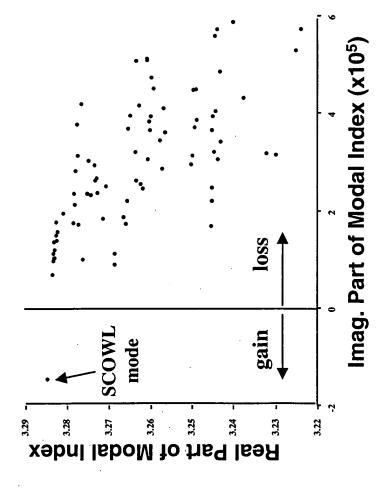


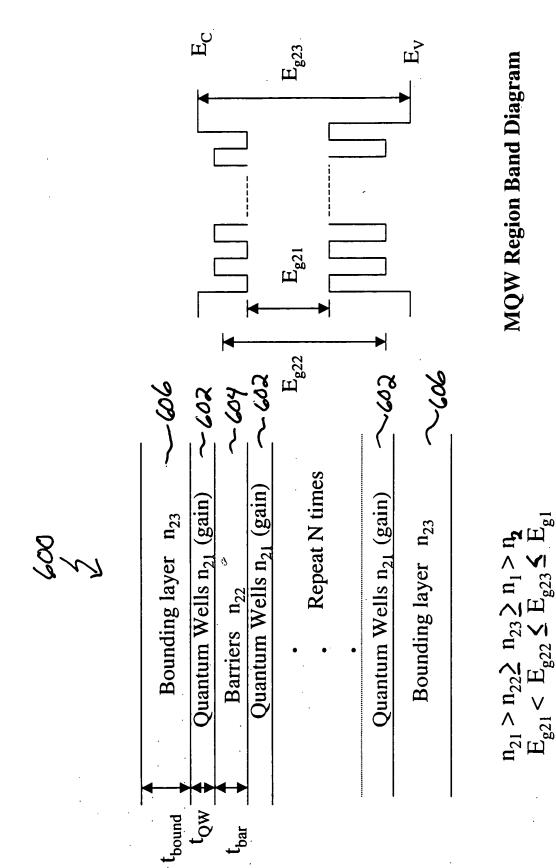


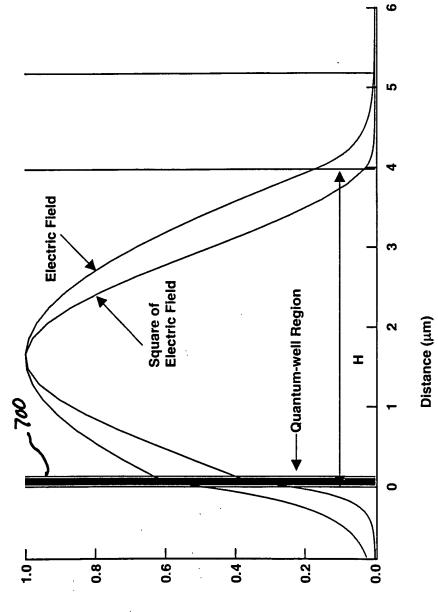
-402 416 n₁ > n₂ p-Type Cap Ľ n2 Low doping=10¹⁷|em-3 n-Type n-Type Buffer and Substrate 413 414 o'ah p-type contact Quantum Well Region 406 Haa 418 R in the 26 **n-type contact Oxide Insulation** GainAsP ЧnР <u>n</u>P . 20: 20: - 80H 101

Fig. 4

FUFFÓ GOCGOCGÓ



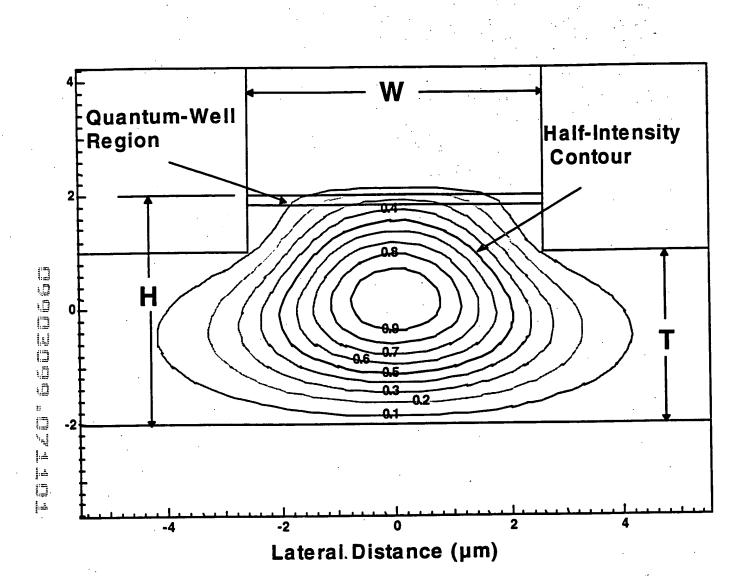




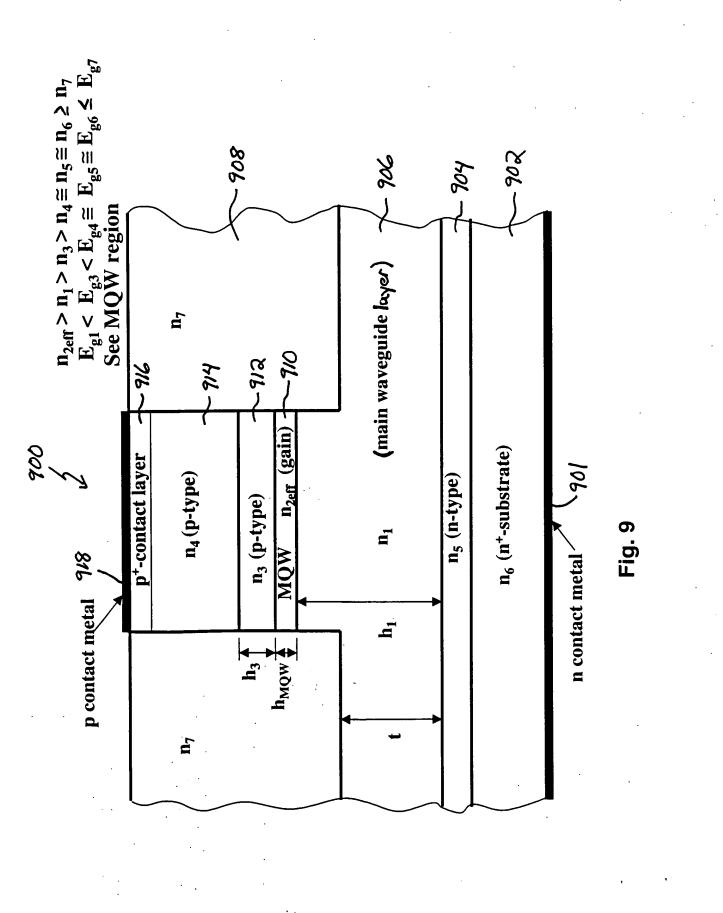
Normalized Electric Field and square of Electric Field

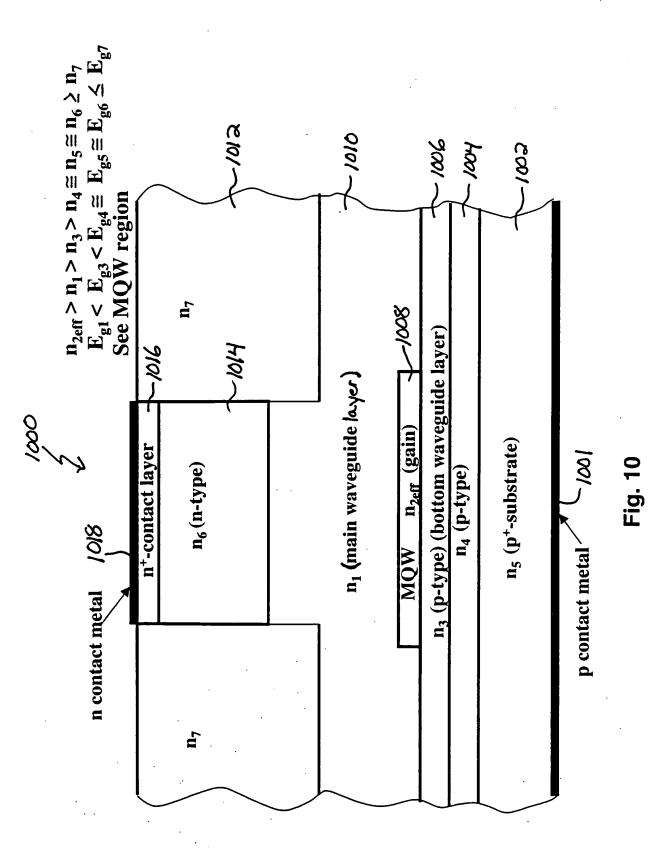
Fig. 7

<u>:</u>•

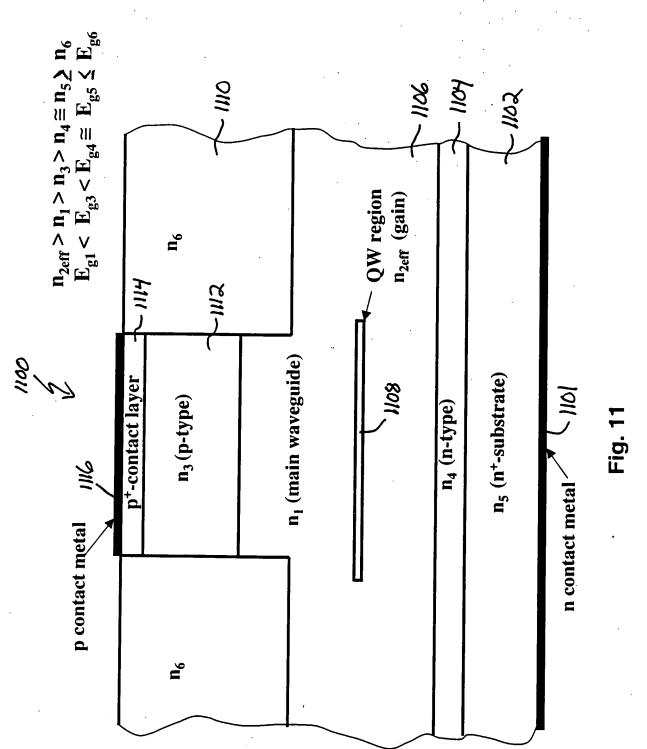








FOFFCO CODCOC



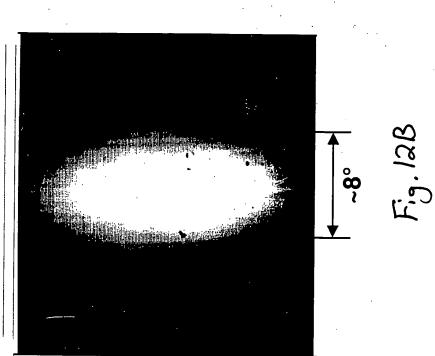
FGTTC" COECOCO

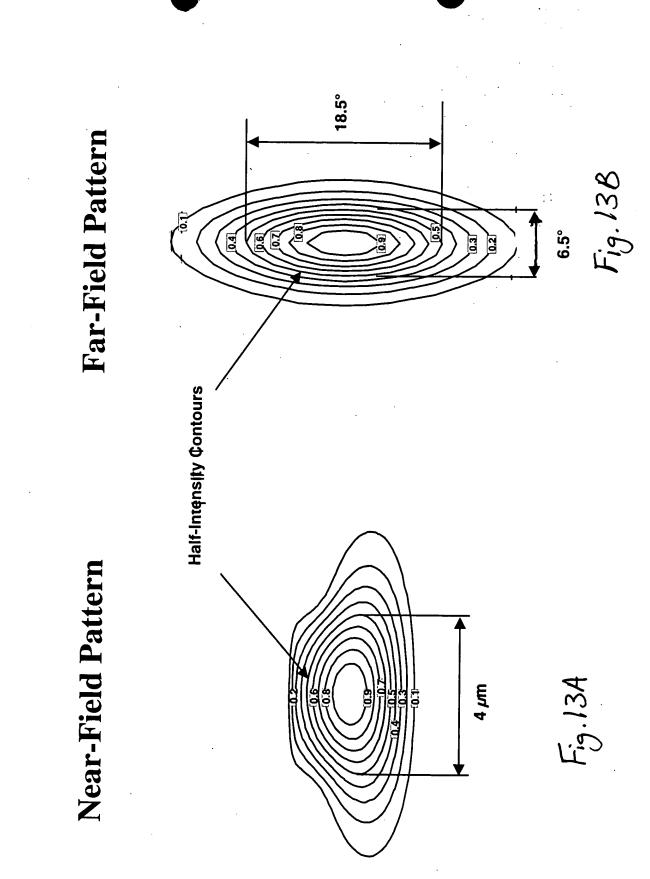
Near-Field Mirror Illumination Pattern



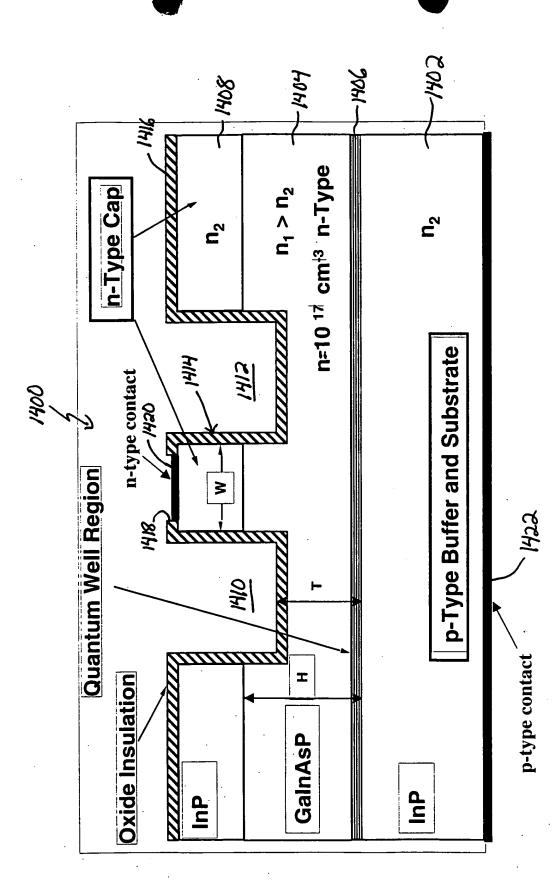
Fig. 12A

Far-Field Pattern

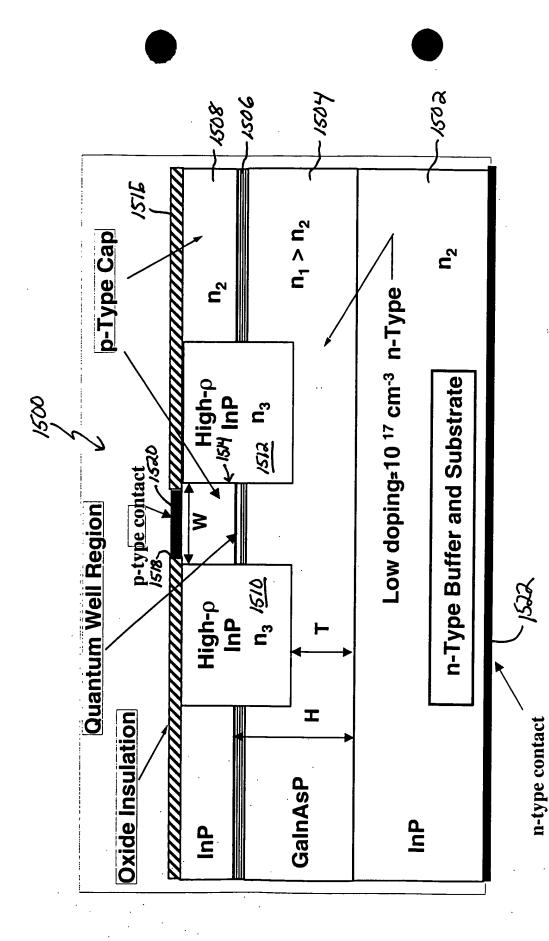




FOFFC COULDOG

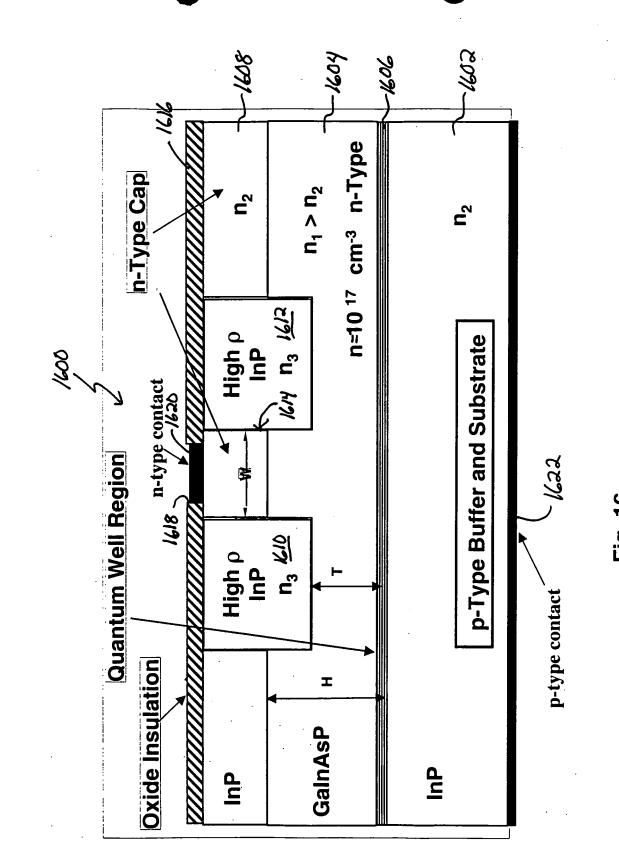


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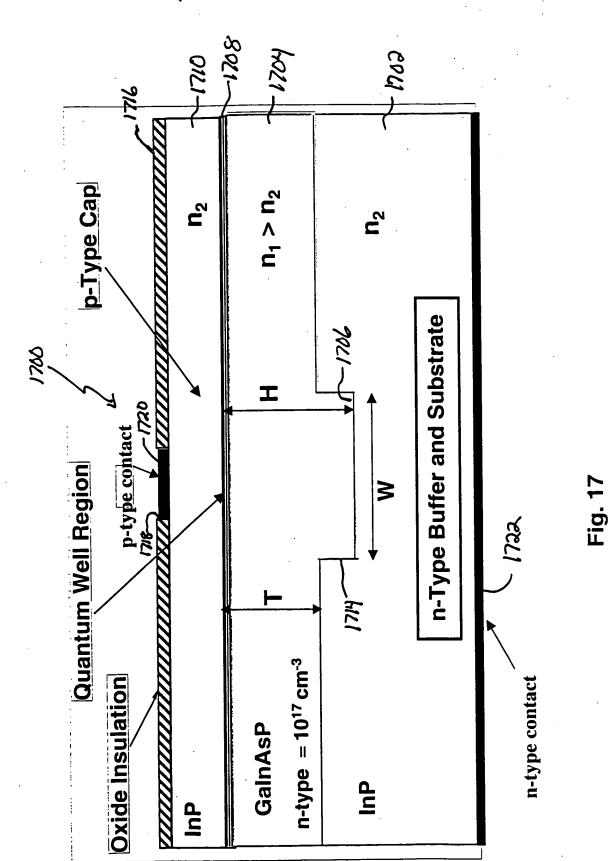




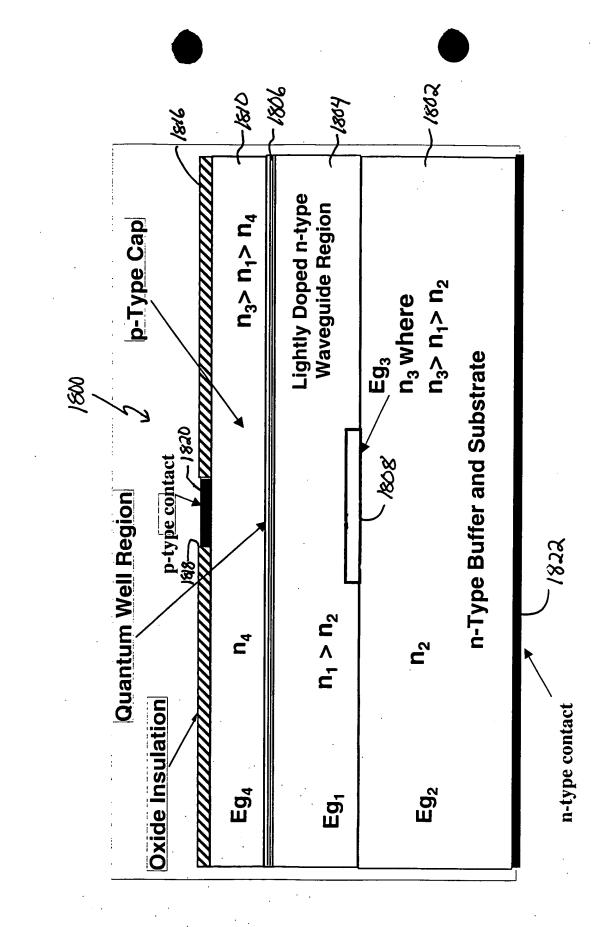
TOFFIC DODEDODED



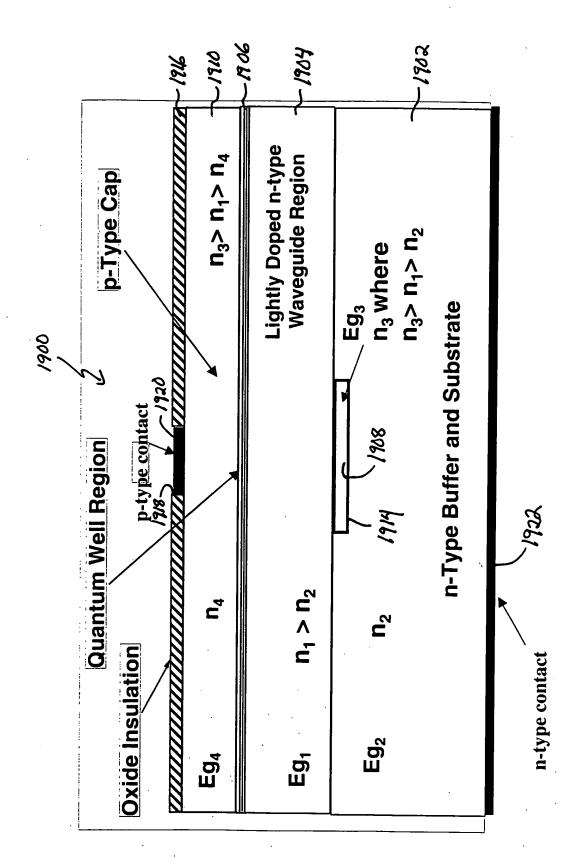
rorre couzoo



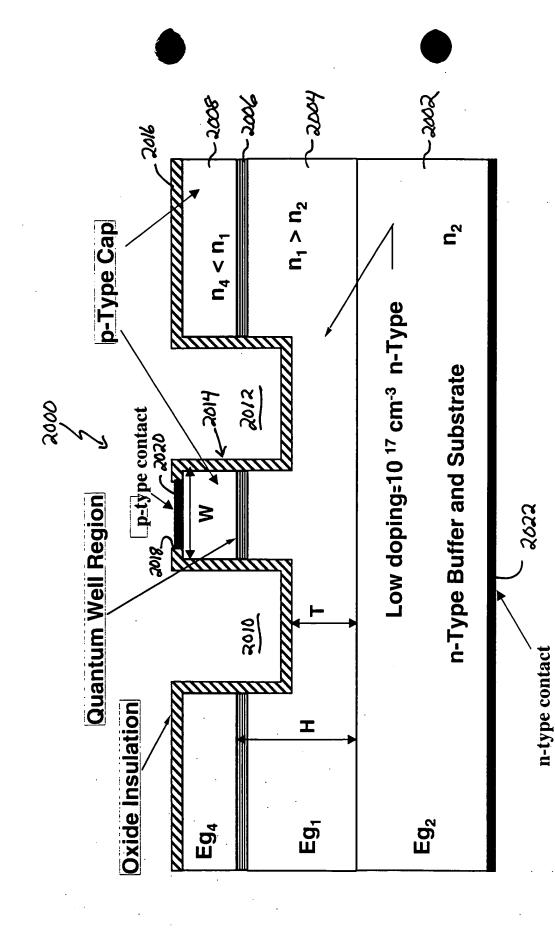
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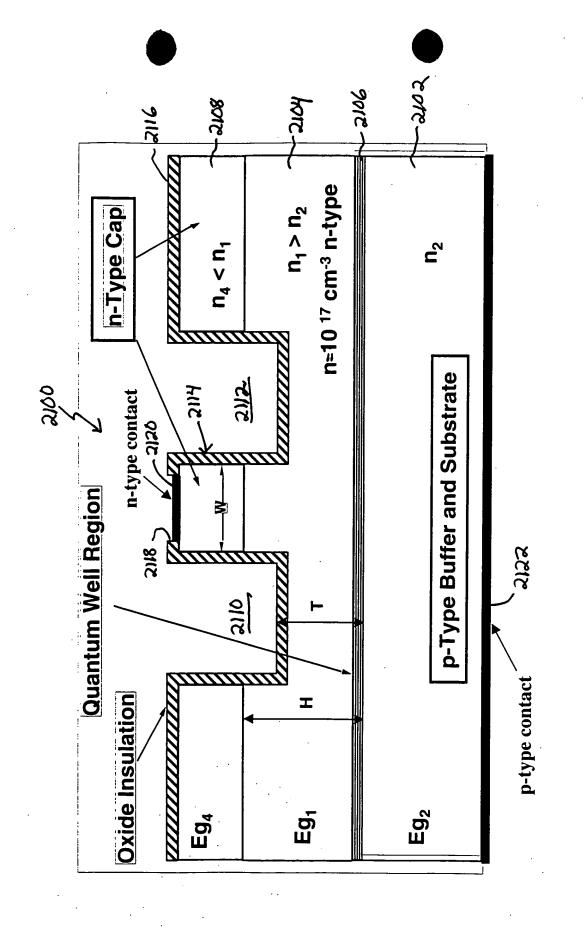
rorro concoch

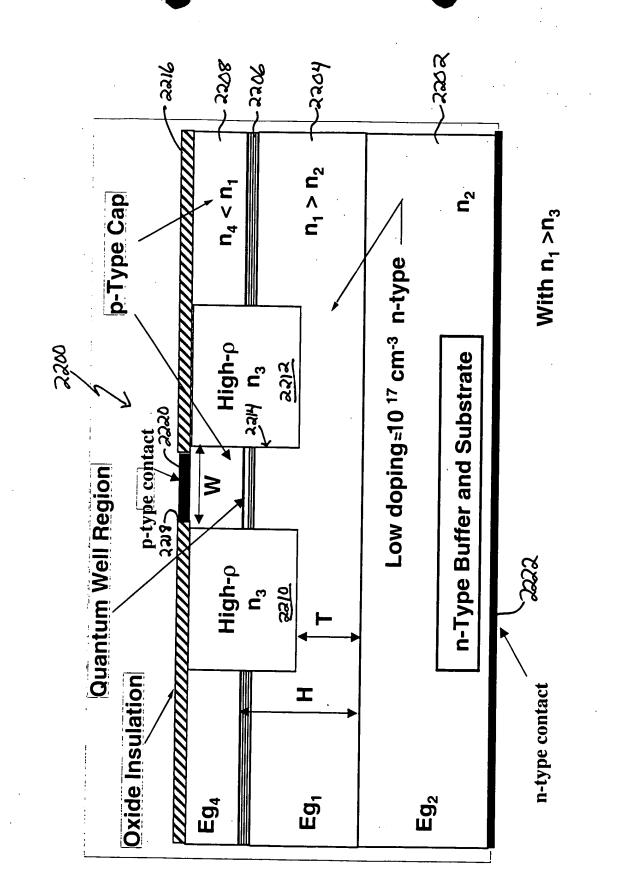


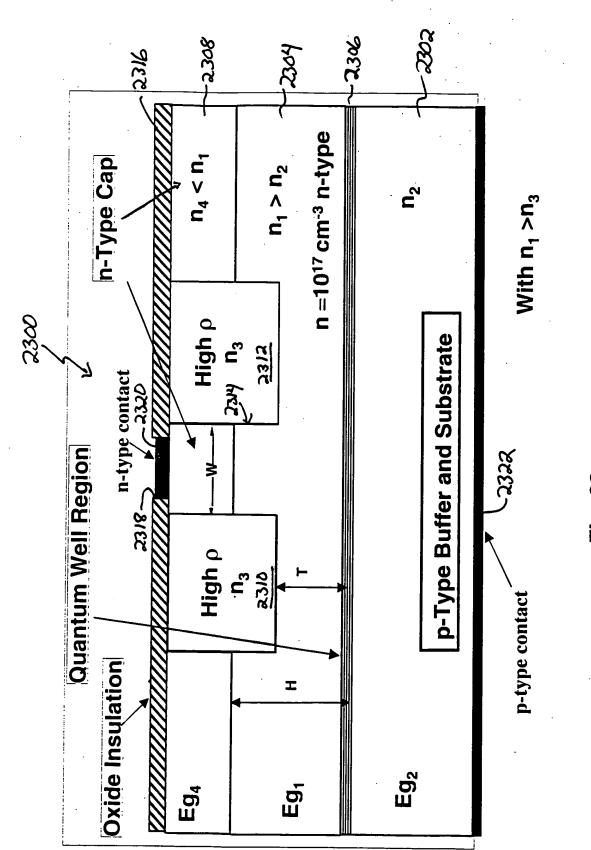




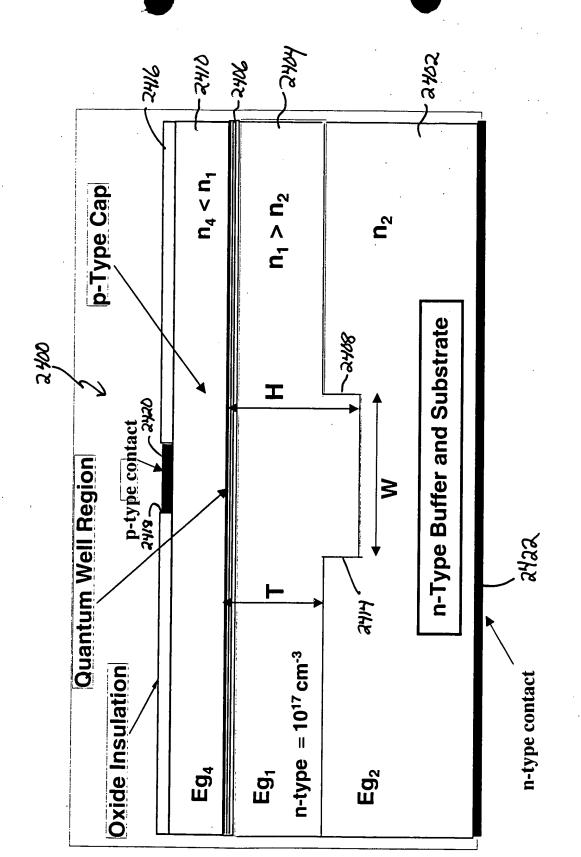
FGFFCG CCCCCCC







TOTTO COTTOC



FCFFC OCCOCOCO

